TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7SZ04F,TC7SZ04FU

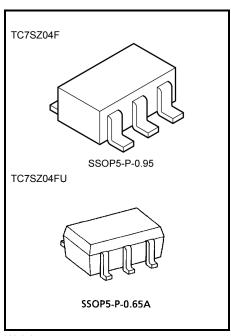
#### Inverter

#### **Features**

- High output drive: ±24 mA (min) at V<sub>CC</sub> = 3 V
- Super high speed operation: t<sub>pd</sub>=2.4 ns (typ.)

at  $V_{CC} = 5 \text{ V}, 50 \text{ pF}$ 

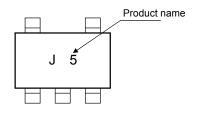
- Operation voltage range: V<sub>CC</sub> (opr) = 1.8~5.5 V
- 5.5-V tolerant inputs
- 5.5-V power down protection output
- Matches the performance of TC74LCX series when operated at 3.3- V V<sub>CC</sub>



Weight

SSOP5-P-0.95 : 0.016 g (typ.) SSOP5-P-0.65A: 0.006 g (typ.)

## Marking

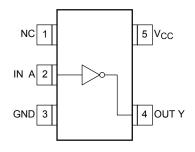


#### Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Supply voltage range	$V_{CC}$	-0.5~6	V	
DC input voltage	V <sub>IN</sub>	-0.5~6	V	
DC output voltage	V <sub>OUT</sub>	-0.5~V <sub>CC</sub> + 0.5	٧	
Input diode current	lıĸ	-20	mA	
Output diode current	I <sub>OK</sub>	±20	mA	
DC output current	lout	±50	mA	
DC V <sub>CC</sub> /ground current	I <sub>CC</sub>	±50	mA	
Power dissipation	PD	200	mW	
Storage temperature	T <sub>stg</sub>	-65~150	°C	
Lead temperature (10 s)	TL	260	°C	

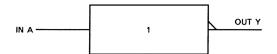
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#### Pin Assignment (top view)





# **Logic Diagram**



#### **Truth Table**

Α	Υ
L	Н
Н	L

# **Recommended Operating Conditions**

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	1.8~5.5	V
		1.5~5.5 (Note 1)	V
Input voltage	V <sub>IN</sub>	0~5.5	V
Output voltage	V <sub>OUT</sub>	0~5.5 (Note 2)	V
		0~V <sub>CC</sub> (Note 3)	V
Operating temperature	T <sub>opr</sub>	-40~85	°C
	dt/dv	$0\sim20~(V_{CC}=1.8~V,2.5~V\pm0.2~V)$	
Input rise and fall time		$0\sim10~(V_{CC}=3.3~V\pm0.3~V)$	ns/V
		$0~5~(V_{CC} = 5.5~V \pm 0.5~V)$	

Note 1: Data retention only

Note 2:  $V_{CC} = 0 V$ 

Note 3: High or Low state

### **Electrical Characteristics**

#### **DC Characteristics**

Characteristics Symbol Test Condition			Ta = 25°C			Ta = −40~85°C		Unit		
		V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Offic		
High-level input voltage VIH —			1.8	V <sub>CC</sub> × 0.88	_	_	V <sub>CC</sub> × 0.88	_	V	
		2.3~5.5		V <sub>CC</sub> × 0.75	_	_	V <sub>CC</sub> × 0.75	_	V	
Low-level input	VIL		1.8	_		V <sub>CC</sub> × 0.12		V <sub>CC</sub> × 0.12	٧	
voltage	۷IL		_	2.3~5.5			V <sub>CC</sub> × 0.25	l	V <sub>CC</sub> × 0.25	V
				1.8	1.7	1.8	_	1.7	_	
			I <sub>OH</sub> = -100 μA	2.3	2.2	2.3		2.2	_	
			10Η = -100 μΑ	3.0	2.9	3.0	_	2.9	_	
High-level	Vou	V <sub>IN</sub> = V <sub>IL</sub>		4.5	4.4	4.5	_	4.4	_	V
output voltage VOH VI	VIN = VIL	$I_{OH} = -8 \text{ mA}$	2.3	1.9	2.15	_	1.9	_	V	
			$I_{OH} = -16 \text{ mA}$	3.0	2.4	2.8	_	2.4	_	
			I <sub>OH</sub> = -24 mA	3.0	2.3	2.68	_	2.3	_	
			$I_{OH} = -32 \text{ mA}$	4.5	3.8	4.2	_	3.8	_	
				1.8	_	0	0.1	_	0.1	
		100 - 4	2.3	_	0	0.1	_	0.1		
			$I_{OL} = 100 \mu A$	3.0	_	0	0.1	_	0.1	.,
Low-level	Va	V V		4.5	_	0	0.1	_	0.1	
output voltage VoL VIN = VIL	VIN = VIL	I <sub>OL</sub> = 8 mA	2.3	_	0.1	0.3	_	0.3	V	
		I <sub>OL</sub> = 16 mA	3.0	_	0.15	0.4	_	0.4		
		I <sub>OL</sub> = 24 mA	3.0	_	0.22	0.55	_	0.55		
		I <sub>OL</sub> = 32 mA	4.5	_	0.22	0.55	_	0.55		
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0-5.5	_	_	±1	_	±10	μА
Power off leakage current	loff	V <sub>IN</sub> or V <sub>OUT</sub> = 5.5 V		0.0	_	_	1	_	10	μА
Quiescent supply current	Icc	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	_	2	_	20	μА

# AC Characteristics (unless otherwise specified, Input: $t_r = t_f = 3$ ns)

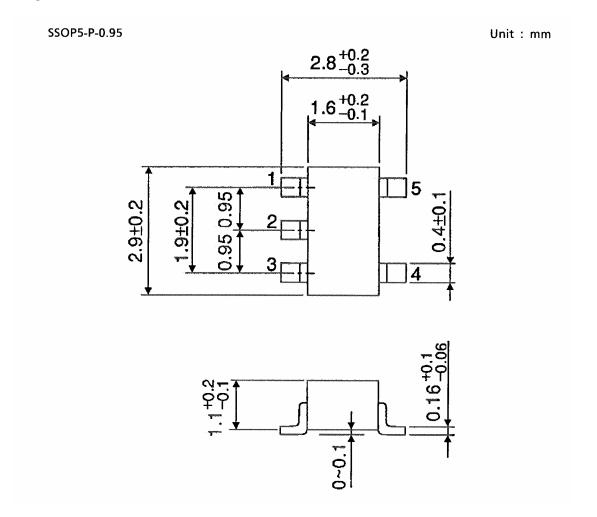
Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40~85°C		Unit	
	Syllibol		V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Offic
Propagation delay time	t <sub>р</sub> LH t <sub>р</sub> HL	$C_L = 15 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	1.8	2.0	4.4	9.5	2.0	10.0	- ns
			$2.5 \pm 0.2$	0.8	2.9	6.5	0.8	7.0	
			$3.3\pm0.3$	0.5	2.1	4.5	0.5	4.7	
			5.0 ± 0.5	0.5	1.8	3.9	0.5	4.1	
		$C_L = 50 \text{ pF},$ $R_L = 500 \Omega$	$3.3\pm0.3$	1.5	2.9	5.0	1.5	5.2	
			$5.0 \pm 0.5$	0.8	2.4	4.3	0.8	4.5	
Input capacitance	C <sub>IN</sub>	_	0~5.5	_	4	_	_	_	pF
Power dissipation capacitance	C <sub>PD</sub>	(Note 4)	3.3		20	_	_	_	pF
			5.5		26	_	_	_	

Note 4: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

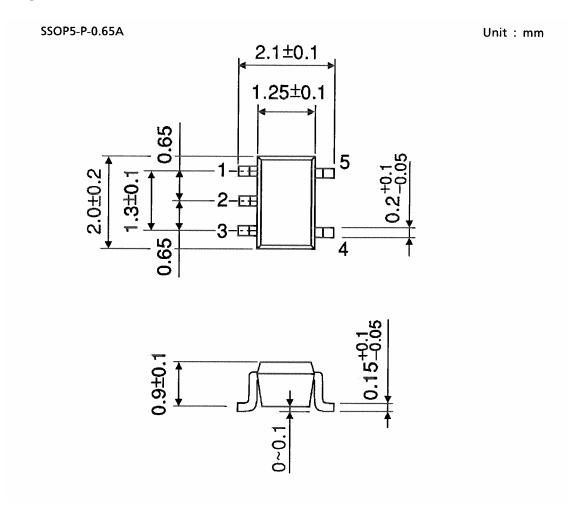
 $I_{CC (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 

# **Package Dimensions**



Weight: 0.016 g (typ.)

# **Package Dimensions**



Weight: 0.006 g (typ.)

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